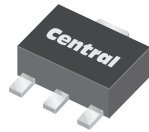


CXDM3069N
SURFACE MOUNT
N-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET



SOT-89 CASE



www.centra-semi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXDM3069N is a high current N-channel enhancement-mode silicon MOSFET, designed for high speed pulsed amplifier and driver applications. This MOSFET offers high current, low $r_{DS(ON)}$, low threshold voltage, and low leakage current.

MARKING: FULL PART NUMBER

APPLICATIONS:

- Load/Power switches
- Power supply converter circuits
- Battery powered portable equipment

FEATURES:

- Low $r_{DS(ON)}$ (50mΩ MAX @ $V_{GS}=2.5V$)
- High current ($I_D=6.9A$)
- Logic level compatibility

MAXIMUM RATINGS: ($T_A=25^{\circ}C$)

Drain-Source Voltage
Gate-Source Voltage
Continuous Drain Current (Steady State)
Maximum Pulsed Drain Current, $t_p=10\mu s$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{DS}	30
V_{GS}	12
I_D	6.9
I_{DM}	40
P_D	1.2
T_J, T_{stg}	-55 to +150
θ_{JA}	104

UNITS

V
V
A
A
W
$^{\circ}C$
$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}C$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=12V, V_{DS}=0$			100	nA
I_{DSS}	$V_{DS}=24V, V_{GS}=0$			1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=250\mu A$	30			V
$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	0.7	0.9	1.4	V
$r_{DS(ON)}$	$V_{GS}=10V, I_D=7.0A$		25	30	mΩ
$r_{DS(ON)}$	$V_{GS}=4.5V, I_D=6.0A$		28	35	mΩ
$r_{DS(ON)}$	$V_{GS}=2.5V, I_D=4.0A$		38	50	mΩ
$Q_g(tot)$	$V_{DS}=15V, V_{GS}=10V, I_D=5.4A$		11		nC
Q_{gs}	$V_{DS}=15V, V_{GS}=10V, I_D=5.4A$		1.0		nC
Q_{gd}	$V_{DS}=15V, V_{GS}=10V, I_D=5.4A$		1.2		nC
C_{rss}	$V_{DS}=15V, V_{GS}=0, f=1.0MHz$		47		pF
C_{iss}	$V_{DS}=15V, V_{GS}=0, f=1.0MHz$		580		pF
C_{oss}	$V_{DS}=15V, V_{GS}=0, f=1.0MHz$		42		pF
t_{on}	$V_{DD}=15V, I_D=1.0A, R_G=15\Omega$		20		ns
t_{off}	$V_{DD}=15V, I_D=1.0A, R_G=15\Omega$		28		ns

R1 (10-August 2012)

CXDM3069N

SURFACE MOUNT

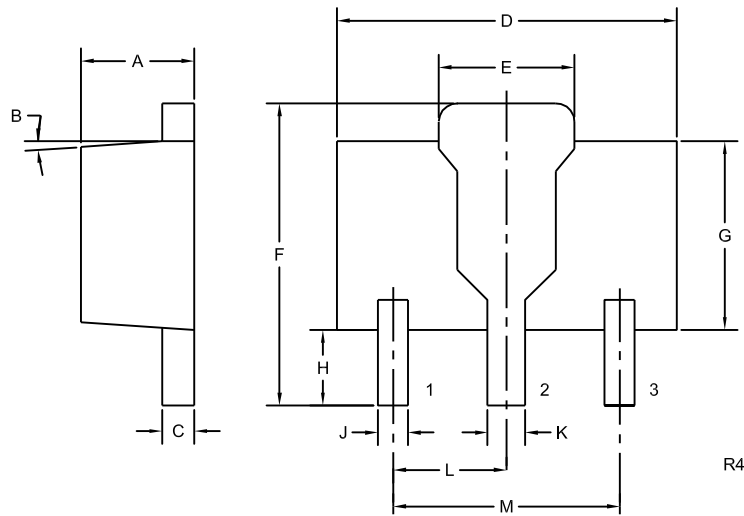
N-CHANNEL

ENHANCEMENT-MODE

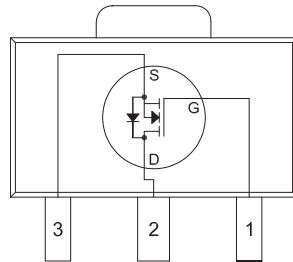
SILICON MOSFET



SOT-89 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



(Top View)

Tab is common to pin 2

LEAD CODE:

- 1) Gate
- 2) Drain
- 3) Source

MARKING: FULL PART NUMBER

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.067	1.40	1.70
B	4°		4°	
C	0.014	0.018	0.35	0.46
D	0.173	0.185	4.40	4.70
E	0.064	0.074	1.62	1.87
F	0.146	0.177	3.70	4.50
G	0.090	0.106	2.29	2.70
H	0.028	0.051	0.70	1.30
J	0.014	0.019	0.36	0.48
K	0.017	0.023	0.44	0.58
L	0.059		1.50	
M	0.118		3.00	

SOT-89 (REV: R4)

R1 (10-August 2012)